MOS LSI

LC89950



1H Delay Line for PAL Systems

Preliminary

Overview

The LC89950 is an IC that provides 1H delay processing for color difference signals used in PAL and SECAM format TV. The LC89950 has two CCD systems, one for the R-Y and one for the B-Y signal, and drives these CCDs with a 4-MHz clock generated within the IC. It uses a sandcastle-shaped three-value input clock with a 1 H (64 μ s) period.

Features

- 5-V single-voltage power supply
- Two input and output systems, one each for R-Y and B-Y signals
- Takes a sandcastle pulse (SCP) as the input clock, and converts that to a burst gate pulse (BGP) signal internally.
- Generates the CCD drive pulses (4 MHz) from the input clock using a PLL circuit.
- Uses BGP as clamp pulses and clamps the no signal section (back porch) once every horizontal scan period.
- The output signal is in-phase with the input signal

Functions

- Two on-chip 254.5-bit CCD shift registers
- CCD drive circuits
- Sample-and-hold circuit
- · Burst gate pulse detection circuit
- $256 \times PLL$ circuit

Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{DD}		-0.3 to +6.0	V
Allowable power dissipation	Pd max		450	mW
Operating temperature	Topr		-10 to +60	°C
Storage temperature	Tstg		-55 to +125	°C

Allowable Operating Ranges at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	min	typ	max	Unit
Supply voltage	V _{DD}		4.75	5.0	5.25	V
Input signal amplitude	V _{INPP(R-Y)}			500	700	mV
	V _{INPP(B-Y)}			500	700	mV

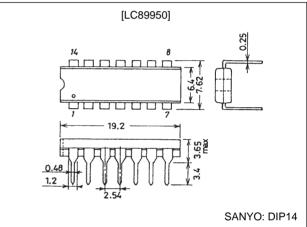
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquarters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN

- Auto-bias and input clamping circuits
- 4-MHz output circuit

Package Dimensions

unit: mm

3003A-DIP14



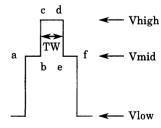
		Switch States								
Parameter	Symbol	SW1	SW2	SW3	SW4	Test conditions	min	typ	max	Unit
Current drain	I _{DD}	a/b	а	a/b	a/b	1	5	10	15	mA
Output pin voltage (pin 1)	V _{OUT} (R-Y)	b	а	a/b	a/b	2	0.7	1.7	2.7	V
Output pin voltage (pin 3)	V _{OUT} (B-Y)	а	а	a/b	a/b	2	0.7	1.7	2.7	V
Input pin voltage (pin 7)	V _{IN} (R-Y)	b	а	a/b	a/b	2	1.4	2.4	3.4	V
Input pin voltage (pin 5)	V _{IN} (B-Y)	а	а	a/b	a/b	2	1.4	2.4	3.4	V
Voltage gain	G _V (R-Y)	а	а	а	а	3	-2	0	+2	dB
	G _V (B-Y)	b	а	а	а	3	-2	0	+2	dB
Differential voltage gain	ΔG_V	a⇔b	а	а	а	3		0.1	0.3	dB
Frequency characteristics	G _f (R-Y)	а	а	а	а	4	-3	-1		dB
	G _f (B-Y)	b	а	а	а	4	-3	-1		dB
Positive phase input linearity +L6	+L6 (R-Y)	а	а	а	b	5	57	60	63	%
	+L6 (B-Y)	b	а	а	b	5	57	60	63	%
Inverted input linearity -L6	–L6 (R-Y)	а	а	b	b	5	57	60	63	%
	–L6 (B-Y)	b	а	b	b	5	57	60	63	%
Clock leakage (4 MHz)	Lclk (R-Y)	а	а	а	а	6		7	12	mVrms
	Lclk (B-Y)	b	а	а	а	6		7	12	mVrms
Noise level	No (R-Y)	а	а	а	b	7		1	2	mVrms
	No (B-Y)	b	а	а	b	7		1	2	mVrms
Output impedance	Z _{OUT} (R-Y)	а	a⇔b	а	а	8	200	300	400	Ω
	Z _{OUT} (B-Y)	b	a⇔b	а	а	8	200	300	400	Ω
Delay time	Td (R-Y)	а	а	а	а	9		63.80		μs
	Td (B-Y)	b	а	а	а	9		63.80		μs

Electrical Characteristics at Ta = 25°C, $V_{\mbox{DD}}$ = 5.0 V, Fscp = 15.625 kHz

Sandcastle Pulse (Input Clock) Conditions

Parameter	Symbol	Conditions	min	typ	max	Unit
Input frequency*1	Fscp		14.625	15.625	16.625	kHz
Input pulse width	TW bgp		3.0	4.0	5.0	μs
High level*2	Vhigh		5.9	6.5	7.5	V
Mid level*3	Vmid		2.5	3.5	4.4	V
Low level	Vlow		-0.3	0	2.5	V

Notes: 1. Indicates the synchronization range for the PLL circuit. The delay time changes with the input frequency.
2. Vhigh is the minimum value between c and d.
3. Vmid is the maximum value between a and b and between e and f.



<Sandcastle Pulse Waveform>

Test Conditions

- 1. Measure the power-supply current when no input signal is supplied.
- 2. Measure the pin voltages on each pin when no input signal is supplied.
- 3. Let V_{OUT} be the OUT pin signal amplitude when a 200-kHz 350-mVp-p sine wave is input.

Then, the voltage gain (G_V) for each of the R-Y and B-Y I/O systems is given by:

$$G_{V} = 20\log \frac{V_{OUT} [mVp-p]}{350 [mVp-p]} [dB]$$

. . .

The R-Y and B-Y voltage gains (ΔG_V) are:

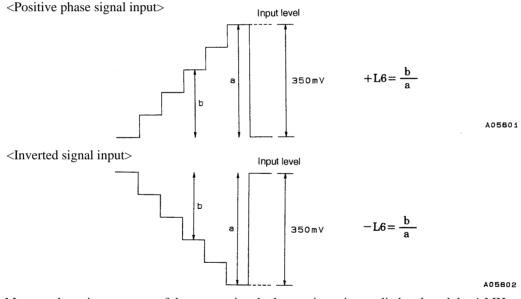
$$\Delta G_{V} = |G_{V}(R-Y) - G_{V}(B-Y)|$$

4. Let V1 be the OUT pin output when a 100-kHz 200-mVp-p sine wave is input.

Let V2 be the OUT pin output when a 1-MHz 200-mVp-p sine wave is input.

$$G_{f} = 20 \log \frac{V2 [mVp-p]}{V1 [mVp-p]} [dB]$$

5. Input a 5-stage step waveform (350 mVp-p) and measure the levels a and b in the output signals. Perform those measurements for both positive phase and inverted signal inputs.



- 6. Measure the noise spectrum of the output signal when no input is supplied and read the 4-MHz peak.
- 7. Pass the output signal through a 2-MHz low-pass filter and a 100-kHz high-pass filter. Then, measure that output with a noise meter, when no input signal is supplied. Use a 2-MHz low-pass filter with an attenuation of -60 dB at 4-MHz.
- 8. Input a 200-kHz 350-mVp-p sine wave.

Let V1 be the OUT pin output when SW2 is set to a.

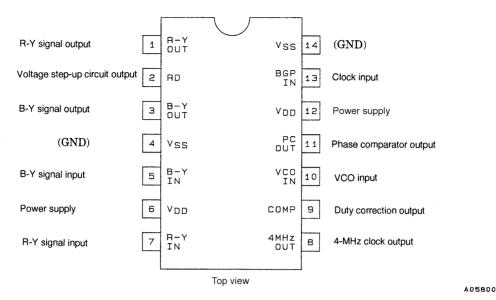
Let V2 be the OUT pin output when SW2 is set to b.

$$Z_{\rm O} = \frac{V1 \ [mVp-p] - V2 \ [mVp-p]}{V2 \ [mVp-p]} \times 500 \ [Ω]$$

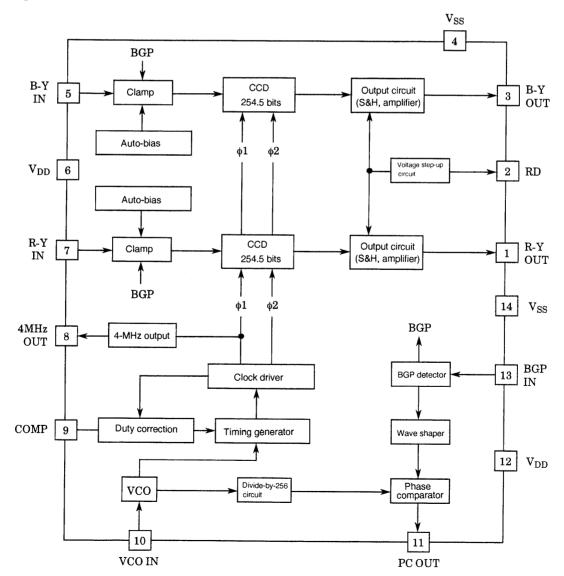
9. Measure the delay time of the OUT pin output with respect to the input signal. When taking this measurement, exclude the delay associated with the low-pass filter.

LC89950

Pin Assignment

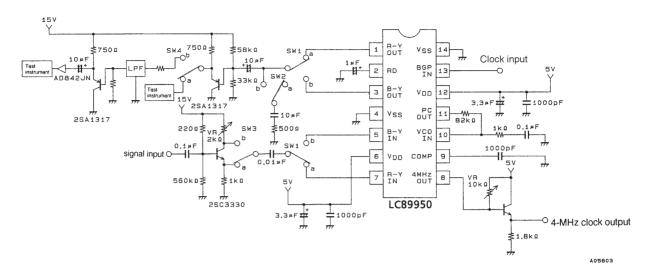


Note: Pins 1 and 3 are referred to collectively as the "OUT pin."



Block Diagram

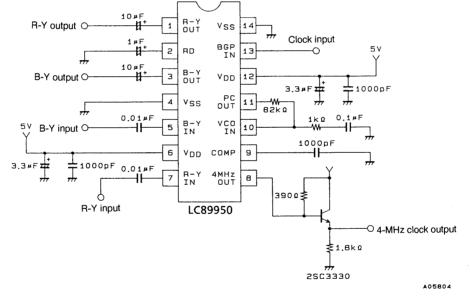
Test Circuit



Notes: 1. Adjust VR (2 k Ω) so that the output amplitudes when SW3 is set to the a and b positions are equal.

- 2. LPF is a 2-MHz low-pass filter. Use a filter with an attenuation of -60 dB at 4 MHz.
- 3. The operational amplifier (AD842JN) is a non-inverting amplifier, and the gain from the SW1 output to the operational amplifier output should be 0 dB.

Sample Application Circuit



- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:
 - ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use:
 - ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of December, 1997. Specifications and information herein are subject to change without notice.

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.